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Kind regards,

Team Nexperia

Product data sheet

Product profile

1.1 General description

NPN medium power transistors in an ultra thin DFN2020D-3 (SOT1061D) leadless small Surface-Mounted Device (SMD) plastic package with medium power capability and visible and solderable side pads.

PNP complement: BC69PAS series

1.2 Features and benefits

- High collector current capability I_C and I_{CM}
- Reduced Printed-Circuit Board (PCB) area requirements
- Exposed heat sink for excellent thermal and electrical conductivity
- AEC-Q101 qualified

- Two current gain selections
- Leadless very small SMD plastic package with medium power capability
- Suitable for Automatic Optical Inspection (AOI) of solder joint

1.3 Applications

- Linear voltage regulators
- Battery driven devices
- MOSFET drivers

- Low-side switches
- Power management
- Amplifiers

1.4 Quick reference data

Quick reference data

T_{amb} = 25 °C unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	20	V
I _C	collector current		-	-	2	Α
I _{CM}	peak collector current	single pulse; $t_p \le 1$ ms	-	-	3	Α
h _{FE}	DC current gain	$V_{CE} = 1 \text{ V; } I_{C} = 500 \text{ mA}$	85	-	375	
	h _{FE} selection -25	$V_{CE} = 1 \text{ V; } I_{C} = 500 \text{ mA}$	160	-	375	

[1] Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02.$



2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	base		
2	emitter	3	3
3	collector	Transparent top view	1

3. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BC68PAS	DFN2020D-3	•	SOT1061D			
BC68-25PAS		package; no leads; 3 terminals; body $2 \times 2 \times 0.65$ mm.				

4. Marking

Table 4. Marking codes

Type number	Marking code
BC68PAS	BY
BC68-25PAS	BZ

5. Limiting values

Table 5. Limiting values

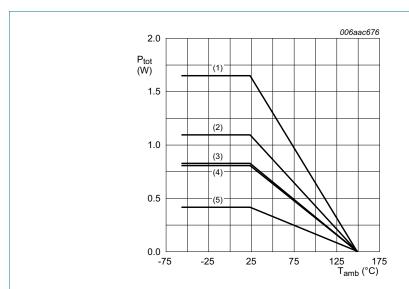
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	32	V
V_{CEO}	collector-emitter voltage	open base	-	20	V
V_{EBO}	emitter-base voltage	open collector	-	5	V
I _C	collector current		-	2	А
I _{CM}	peak collector current	$\begin{array}{l} \text{single pulse;} \\ t_p \leq 1 \text{ ms} \end{array}$	-	3	Α
I _B	base current		-	0.4	А

Table 5. Limiting values ...continued
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	420	mW
			[2]	-	830	mW
			[3]	-	1.1	W
			[4]	-	810	mW
			[5]	-	1.65	W
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 1 cm².
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 6 cm².
- [4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.
- [5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and mounting pad for collector 1 cm².



- (1) FR4 PCB, 4-layer copper, 1 cm²
- (2) FR4 PCB, single-sided copper, 6 cm²
- (3) FR4 PCB, single-sided copper, 1 cm²
- (4) FR4 PCB, 4-layer copper, standard footprint
- (5) FR4 PCB, single-sided copper, standard footprint

Fig 1. Power derating curves

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	298	K/W
			[2]	151	K/W
			[3]	114	K/W
			[4]	154	K/W
			[5]	76	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point	in free air		20	K/W

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 1 cm².
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 6 cm².
- [4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.
- [5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and mounting pad for collector 1 cm²

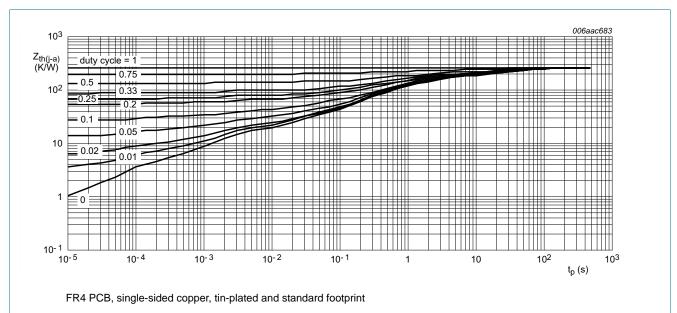
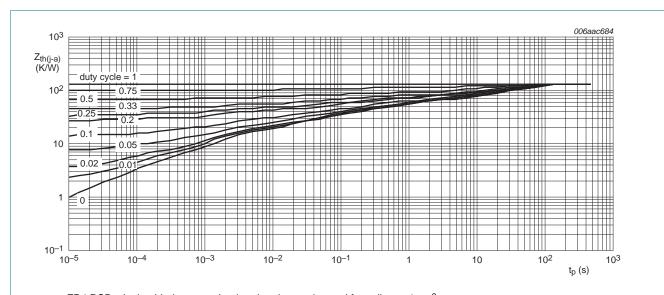
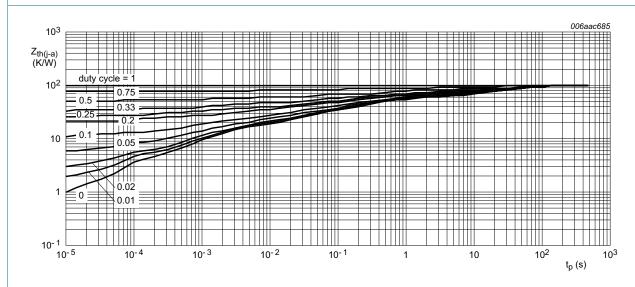


Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration for; typical values



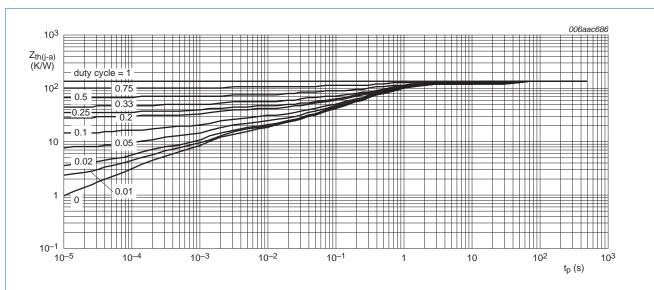
FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 1 cm²

Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration for; typical values



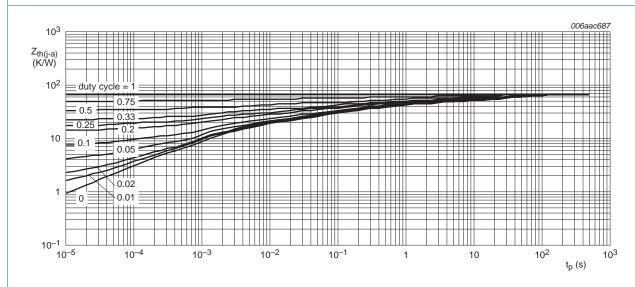
FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 6 cm²

Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration for; typical values



FR4 PCB, 4-layer copper, tin-plated and standard footprint

Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration for; typical values



FR4 PCB, 4-layer copper, tin-plated and mounting pad for collector 1 cm²

Fig 6. Transient thermal impedance from junction to ambient as a function of pulse duration for; typical values

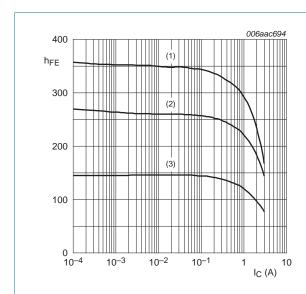
7. Characteristics

Table 7. Characteristics

T_{amb} = 25 °C unless otherwise specified

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CBO} collector-base cut-off current		V _{CB} = 25 V; I _E = 0 A		-	-	100	nA
		$V_{CB} = 25 \text{ V}; I_E = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$		-	-	10	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A		-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 10 V; I _C = 5 mA		50	-	-	
	V _{CE} = 1 V; I _C = 500 mA	<u>[1]</u>	85	-	375		
	V _{CE} = 1 V; I _C = 1 A	<u>[1]</u>	60	-	-		
		V _{CE} = 1 V; I _C = 2 A	<u>[1]</u>	40	-	-	
	h _{FE} selection -25	V _{CE} = 1 V; I _C = 500 mA	<u>[1]</u>	160	-	375	
V _{CEsat}	collector-emitter saturation	I _C = 1 A; I _B = 100 mA	<u>[1]</u>	-	-	0.5	V
	voltage	I _C = 2 A; I _B = 200 mA	<u>[1]</u>	-	-	0.6	V
V_{BE}	base-emitter voltage	$I_C = 5 \text{ mA}; V_{CE} = 10 \text{ V}$	<u>[1]</u>	-	-	0.7	V
	I _C = 1 A; V _{CE} = 1 V	<u>[1]</u>	-	-	1	V	
f _T	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 50 \text{ mA}; f = 100 \text{ MHz}$		40	170	-	MHz
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$ - 22		-	pF		

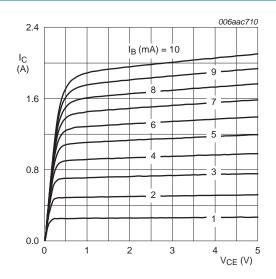
[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$





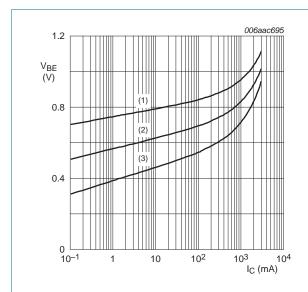
- (1) $T_{amb} = 100 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

Fig 7. DC current gain as a function of collector current; typical values



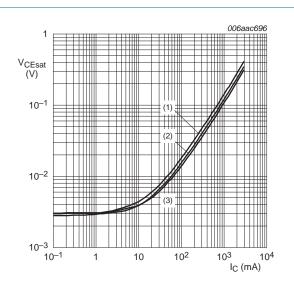
T_{amb} = 25 °C

Fig 8. Collector current as a function of collector-emitter voltage; typical values



- $V_{CE} = 1 V$
- (1) $T_{amb} = -55 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = 100 \, ^{\circ}C$

Fig 9. Base-emitter voltage as a function of collector current; typical values



- $I_{\rm C}/I_{\rm B} = 10$
- (1) $T_{amb} = 100 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

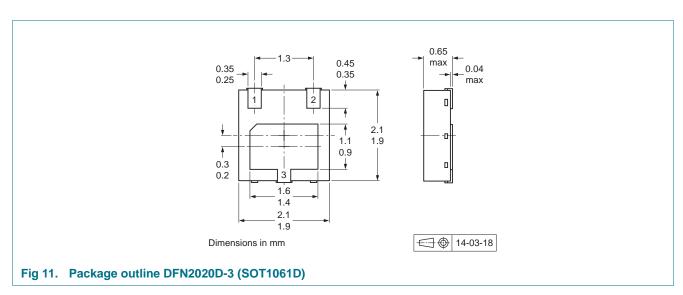
Fig 10. Collector-emitter saturation voltage as a function of collector current; typical values

8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline

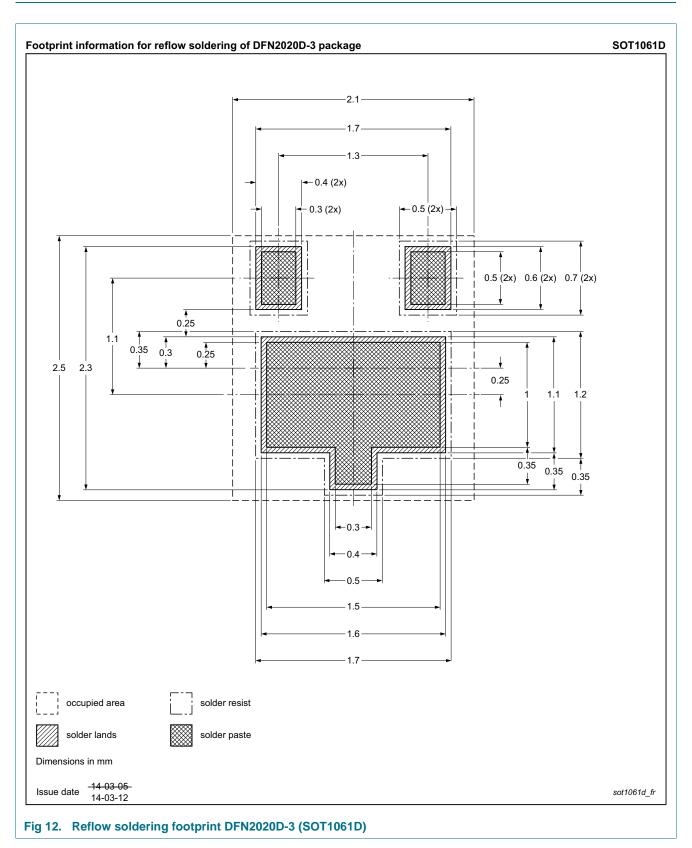


BC68PAS_SER

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10. Soldering



BC68PAS_SER

BC68PAS series

20 V, 2 A NPN medium power transistors

11. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BC68PAS_SER v.1	20150619	Product data sheet	-	-

Product data sheet

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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BC68PAS series

20 V, 2 A NPN medium power transistors

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